

1.6 Ω On Resistance, ± 5 V, +12 V, and +3 V Quad SPST Switches

DESCRIPTION

The DG9424E, DG9425E, DG9426E are monolithic quad single-pole-single-throw analog switches. The G9424E and DG9425E differ only in that they respond to opposite logic levels. The DG9426E has two normally open and two normally closed switches. It can be given various configurations, including four SPST, two SPDT, and one DPDT.

Using BiCMOS wafer fabrication technology allows the DG9424E, DG9425E, and DG9426E to operate on single and dual supplies. Single supply voltage ranges from 3 V to 16 V while dual supply operation is recommended with \pm 3 V to \pm 8 V. Each switch conducts equally well in both direction when on, and blocks input voltages up to the supply levels when off.

The low and flat on resistance over the full input signal voltage rang bring excellent linearity, reduce insertion loss and signal distortion, make them ideal for data acquisition and programmable gain control applications. These switch characters also make them ideal fit for audio signal switch and reed relay replacement.

The DG9424E, DG9425E, DG9426E feature low power dissipation, fast switching speed, and low voltage logic control threshold. Proprietary design enables the low charge injection that minimize the switching transient.

Operation temperature is specified from -40 °C to +85 °C. The DG9424E, DG9425E, DG9426E are available in 16 lead TSSOP packages.

FEATURES

- 3 V to 16 V single supply or ± 3 V thru ± 8 V dual supply operation
- 1.6 Ω typical on resistance
- 3 V logic compatible for control
- Bidirectional rail to rail signal switching
- Fast switching speed
- < 0.2 nA switch on leakage</p>
- Break-before-make switching DG9426

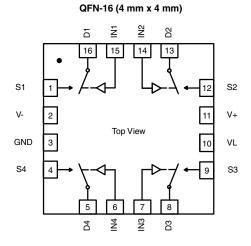
BENEFITS

- Wide operation voltage range
- · Low signal errors and distortion
- Fast switching time
- Simple interfacing

APPLICATIONS

- · Automatic test equipment
- Data acquisition systems
- Meters and instruments
- Medical and healthcare systems
- Communication systems
- Audio and video signal routing
- Relay replacement
- Battery powered systems
- Computer peripherals
- Audio and video signal routing

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

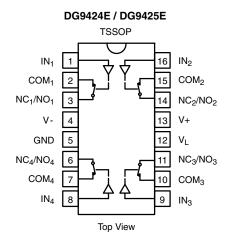


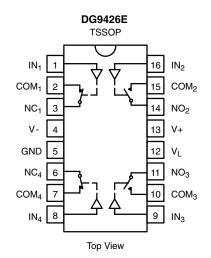
Note

• QFN exposed pad can either be tied to V- or left floating



FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION





TRUTH TABLE				TRUTH TABLE		
LOGIC	DG9424E	DG9425E		LOGIC	SW ₁ , SW ₄	SW ₂ , SW ₃
0	Off	On		0	On	Off
1	On	Off]	1	Off	On

ORDERING INFORMATION									
TEMP. RANGE	PACKAGE	PART NUMBER	PART MARKING	STD PACK QUANTITY					
		DG9424EDQ-T1-GE3	9424E	Tape and reel 3000 units					
	16-pin TSSOP	DG9425EDQ-T1-GE3	9425E	Tape and reel 3000 units					
-40 °C to +85 °C		DG9426EDQ-T1-GE3	9426E	Tape and reel 3000 units					
-40 °C to +85 °C		DG9424EDN-T1-GE4	9424E	Tape and reel 2500 units					
	QFN (4 mm x 4 mm) 16L (variation 2)	DG9425EDN-T1-GE4	9425E	Tape and reel 2500 units					
	(vanation 2)	DG9426EDN-T1-GE4	9426E	Tape and reel 2500 units					

ABSOLUTE MAXIMUM RA	TINGS				
PARAMETER		LIMIT	UNIT		
V+ to V-		-0.3 to +18			
GND to V-		18	V		
VL		(GND - 0.3) to (V+) + 0.3	V		
IN, COM, NC, NO ^a		(V-) - 0.3 to (V+) + 0.3			
Continuous current (NO, NC, COM pi	าร)	100	m (
Peak current, S or D (pulsed 1 ms, 10	% duty cycle)	200	mA		
Storage temperature		-65 to +150	°C		
Power dissipation (package) ^b		450	mW		
Thermal resistance ^b	Thermal resistance ^b		°C/W		
ESD human body model (HBM); per A	NSI / ESDA / JEDEC [®] JS-001	>1500	V		
Latch up current, per JESD78D		400	mA		

Notes

a. Signals on NC, NO, COM or IN exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings

b. All leads welded or soldered to PC board

c. Derate 7 mW/°C above 25 °C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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DG9424E, DG9425E, DG9426E

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SPECIFICATIONS ^a Single Supply 12 V							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP. ^b	LIMITS -40 °C to +85 °C			UNIT
		$V_{+} = 12 V, V_{-} = 0 V$ $V_{L} = 5 V, V_{IN} = 2.4 V, 0.8 V f$		MIN. d	TYP. ℃	MAX. d	
Analog Switch							
Analog signal range ^e	V _{ANALOG}		Full	0	-	12	V
On-resistance	R _{ON}	$V{+} = 10.8 \text{ V}, V{-} = 0 \text{ V}, \\ I_{\text{NO}}, I_{\text{NC}} = 50 \text{ mA}, V_{\text{COM}} = 2/9 \text{ V}$	Room Full	-	1.6 -	3 4	Ω
Digital Control							
Input current	I _{INL} or I _{INH}		Full	-1	0.01	1	μA
Dynamic Characteristics	•				•		
Turn-on time ^e	+		Room	-	36	51	
rum-on time s	t _{ON}	R _L = 300 Ω, C _L = 35 pF,	Full	-	-	65	
Turn-off time ^e	+	V_{NO} , V_{NC} = 5 V, see Fig. 2	Room	-	20	35	ns
Turn-oπ time °	t _{OFF}		Full	-	-	44	
Break-before-make time delay ^e	t _D	DG9426E only, V_{NO} , V_{NC} = 5 V, R _L = 300 Ω , C _L = 35 pF	Room	2	-	-	
Charge injection ^e	Q _{INJ}	$V_{g} = 0 V, R_{g} = 0 \Omega, C_{L} = 1 nF$	Room	-	38	-	рС
Off-isolation ^e	OIRR	$R_{L} = 50 \Omega$, $C_{L} = 5 pF$,	Room	-	-56	-	dB
Channel-to-channel crosstalk ^e	X _{TALK}	f = 1 MHz	Room	-	-77	-	uБ
NO, NC off capacitance ^e	C _{NO(off)}		Room	-	49	-	- 5
NO, NO OII Capacitance -	C _{NC(off)}	f = 1 MHz				-	
COM off capacitance ^e	C _{COM(off)}		Room	-	37	-	pF
Channel on capacitance ^e	C _{COM(on)}		Room	-	89	-	
Power Supplies							
Positive supply current	l+		Room	-	0.02	1	
Positive supply current	1+		Full	-	-	5	
Negative supply surrent	-		Room	-1	-0.002	-	
Negative supply current	1-		Full	-5	-	-	μA
Logic supply current	L.	$V_{IN} = 0 \text{ or } V_L$	Room	-	0.002	1	
	۱L		Full	-	-	5	
Ground current	loup		Room	-1	-0.002	-]
	I _{GND}		Full	-5	-	-	

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DG9424E, DG9425E, DG9426E

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SPECIFICATIONS ^a Dual Supply ± 5 V							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP. ^b	LIMITS -40 °C to +85 °C			UNIT
	••••••	V+ = 5 V, V- = 5 V V _L = 5 V, V _{IN} = 2.4 V, 0.8 V ^f		MIN. ^d	۲YP. ۵	MAX. d	0
Analog Switch							
Analog signal range ^e	V _{ANALOG}		Full	-5		5	V
On-resistance	R _{ON}	V+ = 4.5 V, V- = -4.5 V, I _{NO} , I _{NC} = 50 mA	Room Full	-	1.9 -	3.3 4.3	Ω
	I _{NO(off)}		Room	-1	-	1	
	I _{NC(off)}	V+ = 5.5 V. V- = -5.5 V.	Full	-10	-	10	
Switch off leakage current		$V_{COM} = \pm 4.5 \text{ V}, V_{NO}, V_{NC} = \pm 4.5 \text{ V}$	Room	-1	-	1	
	I _{COM(off)}		Full	-10	-	10	nA
		V+ = 5.5 V. V- = -5.5 V.	Room	-1	-	1	†
Channel on leakage current	I _{COM(on)}	V_{NO} , $V_{NC} = V_{COM} = \pm 4.5 V$	Full	-10	-	10	
Digital Control	•				•	•	
Input current ^a	$I_{\rm INL}$ or $I_{\rm INH}$		Full	-1	0.05	1	μA
Dynamic Characteristics							
Turn-on time ^e	+	R_L = 300 Ω, C_L = 35 pF, V _{NO} , V _{NC} = ± 3.5 V, see Fig. 2	Room	-	48	67	ns
Turn-on time °	t _{ON}		Full	-	-	81	
Turn-off time ^e	t _{OFF}		Room	-	34	57	
			Full	-	-	67	110
Break-before-make time delay ^e	t _D	DG9426E only, V _{NO} , V _{NC} = 3.5 V, R _L = 300 Ω , C _L = 35 pF	Room	2	-	-	
Charge injection ^e	Q _{INJ}	V_g = 0 V, R_g = 0 Ω , C_L = 1 nF	Room	-	112	-	рС
Off isolation ^e	OIRR	R _I = 50 Ω, C _I = 5 pF, f = 1 MHz	Room	-	-56	-	dB
Channel-to-channel crosstalk ^e	X _{TALK}	$n_{\rm L} = 30.32, 0_{\rm L} = 3.01, 1 = 1.0012$	Room	-	-82	-	uВ
Source off capacitance ^e	$\begin{array}{c} C_{NO(off)} \\ C_{NC(off)} \end{array}$	<i></i>	Room	-	38	-	1
Drain off capacitance ^e	C _{COM(off)}	f = 1 MHz	Room	-	38	-	pF
Channel on capacitance ^e	C _{COM(on)}		Room	-	89	-	
Power Supplies							
Positive supply surront ^e	l+		Room	-	0.03	1	
Positive supply current ^e	I+		Full	-	-	5	
Negative supply current e	I-		Room	-1	-0.002	-	
	1-	$V_{IN} = 0$ or V_L	Full	-5	-	-	μA
Logic supply current ^e	١L		Room	-	0.002	1	μA
	[.] 'L		Full	-	-	5	
Ground current ^e	IOND		Room	-1	-0.002	-	
	I _{GND}		Full	-5	-	-	



DG9424E, DG9425E, DG9426E

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SPECIFICATIONS ^a Single Supply 5 V								
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 5 V, V- = 0 V	TEMP. ^b	LIMITS -40 °C to +85 °C			UNIT	
		$V_{\rm L} = 5 V, V_{\rm IN} = 2.4 V, 0.8 V^{\rm f}$		MIN. ^d	TYP. °	MAX. d		
Analog Switch								
Analog signal range ^e	VANALOG		Full	-	-	5	V	
On-resistance ^e	R _{ON}	$V_{+} = 4.5 V, I_{NO}, I_{NC} = 50 mA$	Room	-	3.1	4.8	Ω	
On resistance	TON	$V_{+} = 4.5 V, 1_{NO}, 1_{NC} = 30 Hirt$	Full	-	-	5.8	32	
Dynamic Characteristics								
Turn-on time ^e	t _{ON}	R _L = 300 Ω, C _L = 35 pF, V _{NO} , V _{NC} = 3.5 V, see Fig. 2	Room	-	62	78		
	UN		Hot	-	-	106	ns	
Turn-off time ^e	t _{OFF}		Room	-	29	44		
rum-on time *			Hot	-	-	56		
Break-before-make time delay ^e	t _D	DG9426E only, V _{NO} , V _{NC} = 3.5 V, R _L = 300 Ω , C _L = 35 pF	Room	5	-	-		
Charge injection ^e	Q _{INJ}	$V_g = 0 V, R_g = 0 \Omega, C_L = 1 nF$	Room	-	10	-	рС	
Power Supplies								
Positive supply current ^e	l+		Room	-	0.02	1		
Fositive supply current -	1+		Hot	-	-	5		
Negative supply current ^e	I-		Room	-1	-0.002	-		
Negative supply current -	1-	$V_{IN} = 0$ or V_{I}	Hot	-5	-	-	μA	
Logic supply current ^e	ار		Room	-	0.002	1	μn	
	۰ <u>۲</u>		Hot	-	-	5		
Ground current ^e	loup		Room	-1	-0.002	-		
	I _{GND}		Hot	-5	-	-		



DG9424E, DG9425E, DG9426E

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SPECIFICATIONS ^a Single Supply 3 V								
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP. ^b	LIMITS -40 °C to +85 °C			UNIT	
		V+ = 3 V, V- = 0 V V _L = 3 V, V _{IN} = 2.4 V, 0.4 V ^f		MIN. d	TYP. °	MAX. d	o.u.r	
Analog Switch								
Analog signal range ^e	V _{ANALOG}		Full	0	-	3	V	
On-resistance	R _{ON}	V+ = 2.7 V, V- = 0 V.	Room	-	6	-	Ω	
on resistance	NON	I_{NO} , I_{NC} = 5 mA, V_{COM} = 0.5, 2.2 V	Full	-	-	-	32	
	I _{NO(off)}		Room	-1	-	1		
Switch off leakage current a	I _{NC(off)}	V+ = 3.3 V, V- = 0 V.	Full	-10	-	10	nA	
Switch on leakage current		$V_{COM} = 0.3, 3 V, V_{NO}, V_{NC} = 3, 0.3 V$	Room	-1	-	1		
	I _{COM(off)}		Full	-10	-	10		
Channel on leakage current ^a	I _{COM(on)}		Room	-1	-	1		
Charmer on leakage current -			Full	-10	-	10		
Digital Control ^e								
Input current	$I_{\rm INL}$ or $I_{\rm INH}$		Full	-1	0.005	1	μA	
Dynamic Characteristics							-	
Turn-on time	t _{ON}		Room	-	140	-	ns	
	⁴ ON	$R_L = 300 \ \Omega, \ C_L = 35 \ pF.$	Full	-	-	193		
Turn-off time	toff	V_{NO} , V_{NC} = 1.5 V, see Fig. 2	Room	-	65	-		
	UFF		Full	-	-	89		
Break-before-make time delay	t _D	DG9426E only, V _{NO} , V _{NC} = 1.5 V, R _L = 300 Ω , C _L = 35 pF	Room	5				
Charge injection ^e	Q _{INJ}	$V_{g} = 0 V, R_{g} = 0 \Omega, C_{L} = 1 nF$	Room	-	15	-	рС	
Off isolation ^e	OIRR	$R_{L} = 50 \Omega, C_{L} = 5 pF,$	Room	-	-56	-	dB	
Channel-to-channel crosstalk ^e	X _{TALK}	f = 1 MHz	Room	-	-80	-	αв	
Source off capacitance ^e	C _{NO(off)}		Beer		53			
	C _{NC(off)}	f = 1 MHz	Room	-	55	-	nE	
Drain off capacitance ^e	C _{COM(off)}		Room	I	42	-	pF	
Channel on capacitance ^e C _{COM(on)}			Room	-	92	-		

Notes

a. Leakage parameters are guaranteed by worst case test conditions and not subject to production test

b. Room = 25 °C, Full = As determined by the operating temperature suffix

c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing

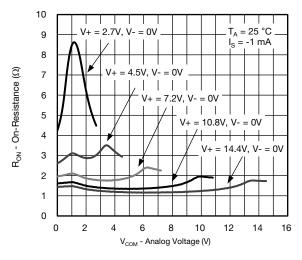
d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet

e. Guaranteed by design, not subject to production test

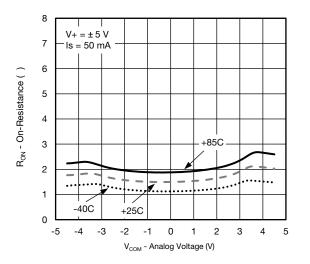
f. V_{IN} = Input voltage to perform proper function



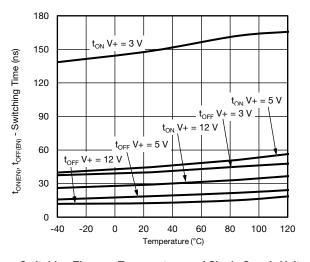
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



 R_{ON} vs. V_{COM} and Supply Voltage



R_{ON} vs. Analog Voltage and Temperature

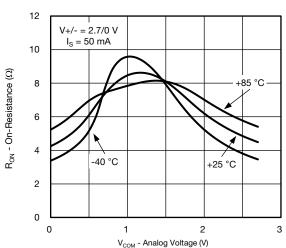




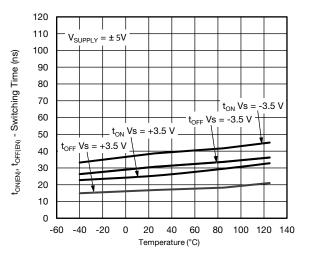
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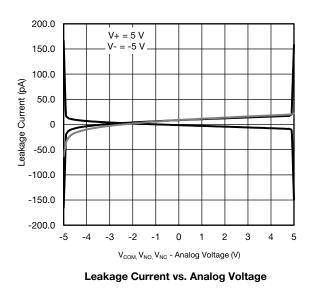
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R_{ON} vs. Analog Voltage and Temperature



Switching Time vs. Temperature and Dual Supply Voltage



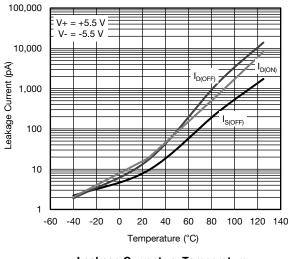
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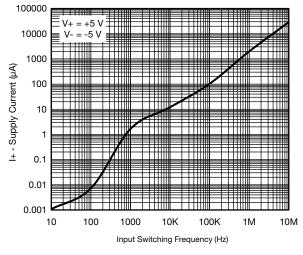
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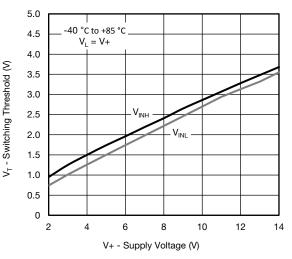
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



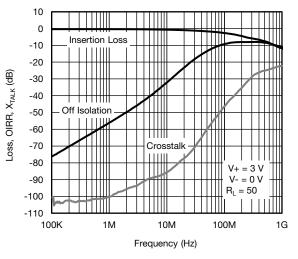
Leakage Current vs. Temperature



Switching Current vs. Input Switching Frequency



Switching Threshold vs. Supply Voltage



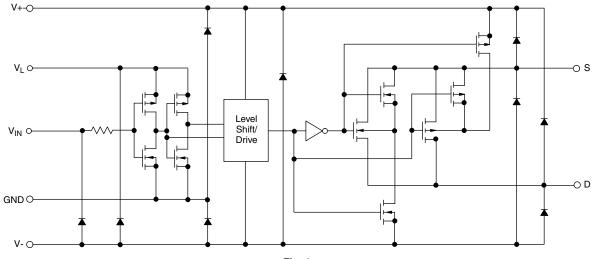
Insertion Loss, Off Isolation and Crosstalk vs. Frequency



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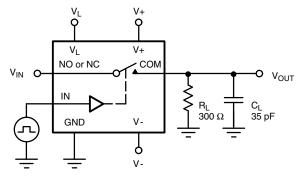
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SCHEMATIC DIAGRAM (typical channel)



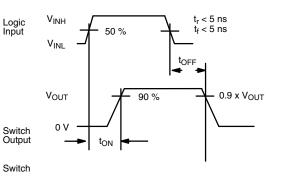


TEST CIRCUITS

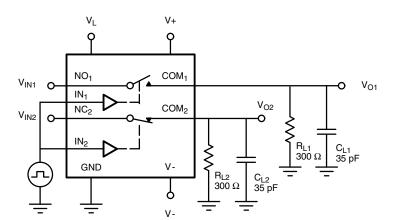


CL (includes fixture and stray capacitance)

 $V_{OUT} = V_{IN} - \frac{R_L}{R_L + r_{ON}}$



Note: Logic input waveform is inverted for switches that have the opposite logic sense control



C_L (includes fixture and stray capacitance)

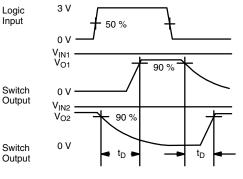


Fig. 3 - Break-Before-Make (DG9426E)

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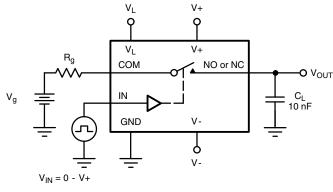
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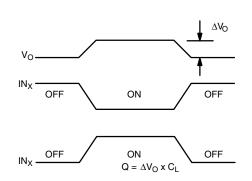
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Fig. 2 - Switching Time



TEST CIRCUITS





 $\ensuremath{\text{IN}_{\text{X}}}$ dependent on switch configuration Input polarity determined by sense of switch.

Fig. 4 - Charge Injection

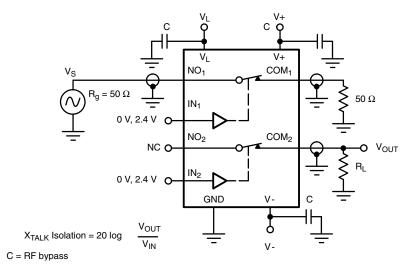
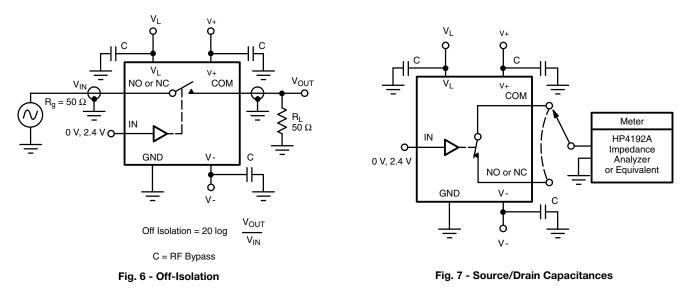


Fig. 5 - Crosstalk



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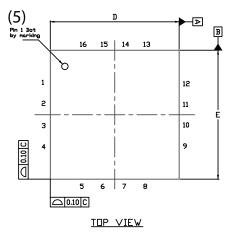
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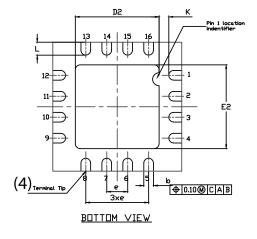
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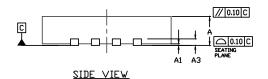
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QFN 4x4-16L Case Outline







VARIATION 1 VARIATION 2 MILLIMETERS(1) MILLIMETERS(1) DIM INCHES INCHES MIN. NOM. MAX. MIN. NOM. MAX. MIN. NOM. MAX. MIN. NOM. MAX. 0.75 0.85 0.95 0.029 0.033 0.037 0.75 0.85 0.95 0.029 0.033 0.037 А 0 -0.05 0 0.002 0 0.05 _ 0.002 A1 -_ 0 A3 0.20 ref. 0.008 ref. 0.20 ref. 0.008 ref. b 0.25 0.30 0.35 0.010 0.012 0.014 0.25 0.30 0.35 0.010 0.012 0.014 4.00 BSC D 0.157 BSC 4.00 BSC 0.157 BSC 0.087 0.106 2.1 2.2 0.083 2.6 2.7 0.102 D2 2.0 0.079 2.5 0.098 0.65 BSC 0.026 BSC 0.65 BSC 0.026 BSC е Е 4.00 BSC 0.157 BSC 4.00 BSC 0.157 BSC 0.087 2.1 2.2 0.083 2.7 0.102 0.106 2.6 E2 2.0 0.079 2.5 0.098 0.20 min. 0.008 min 0.20 min. 0.008 min. Κ 0.5 0.7 0.020 0.024 0.028 0.5 0.016 0.020 L 0.6 0.3 0.4 0.012 N⁽³⁾ 16 16 16 16 Nd⁽³⁾ 4 4 4 4 Ne⁽³⁾ 4 4 4 4

Notes

⁽¹⁾ Use millimeters as the primary measurement.

⁽²⁾ Dimensioning and tolerances conform to ASME Y14.5M. - 1994.

⁽³⁾ N is the number of terminals. Nd and Ne is the number of terminals in each D and E site respectively.

⁽⁴⁾ Dimensions b applies to plated terminal and is measured between 0.15 mm and 0.30 mm from terminal tip.

⁽⁵⁾ The pin 1 identifier must be existed on the top surface of the package by using identification mark or other feature of package body.

⁽⁶⁾ Package warpage max. 0.05 mm.

ECN: S13-0893-Rev. B, 22-Apr-13 DWG: 5890

1

Document Number: 71921

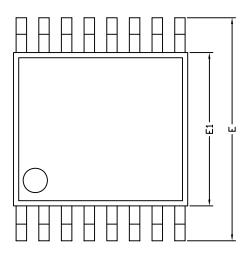
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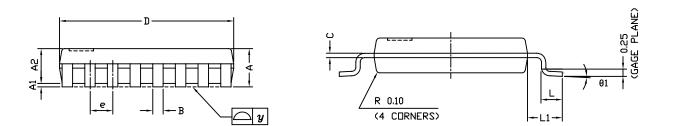


Package Information

Vishay Siliconix

TSSOP: 16-LEAD





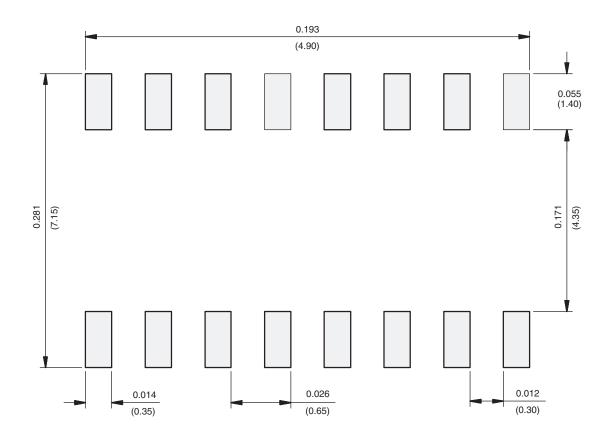
	DIMENSIONS IN MILLIMETERS						
Symbols	Min	Nom	Мах				
A	-	1.10	1.20				
A1	0.05	0.10	0.15				
A2	-	1.00	1.05				
В	0.22	0.28	0.38				
С	-	0.127	-				
D	4.90	5.00	5.10				
E	6.10	6.40	6.70				
E1	4.30	4.40	4.50				
е	-	0.65	-				
L	0.50	0.60	0.70				
L1	0.90	1.00	1.10				
у	-	-	0.10				
θ1	0°	3°	6°				
ECN: S-61920-Rev. D, 23 DWG: 5624	-Oct-06						



PAD Pattern

Vishay Siliconix

RECOMMENDED MINIMUM PAD FOR TSSOP-16



Recommended Minimum Pads Dimensions in inches (mm)



Vishay

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